

# PolarHT<sup>™</sup> Power MOSFET

## IXTQ 64N25P IXTT 64N25P

 $V_{DSS} = 250 V_{D25} = 64 A_{D25} \leq 49 m\Omega$ 

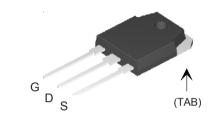
N-Channel Enhancement Mode Avalanche Rated



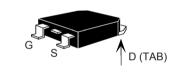
Symbol	Test Conditions	Maximum Ratings		
V <sub>DSS</sub>	$T_{J} = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}$	250	V	
V <sub>DGR</sub>	$T_{J} = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}; R_{GS} = 1 \text{ M}\Omega$	250		
V <sub>GSS</sub>	Continuous	±20	V	
V <sub>GSM</sub>	Transient	±30		
I <sub>D25</sub>	$T_{c} = 25^{\circ} C$	64	A	
I <sub>DM</sub>	$T_{c} = 25^{\circ} C$ , pulse width limited by $T_{IM}$	160	A	
I <sub>AR</sub>	$T_{c} = 25^{\circ}C$	60	А	
E <sub>AR</sub>	$T_c = 25^{\circ} C$	40	mJ	
	$T_c = 25^{\circ} C$	1.0	J	
dv/dt	$I_{S} \leq I_{DM}$ , di/dt $\leq 100$ A/ $\mu$ s, $V_{DD} \leq V_{DSS}$ , $T_{J} \leq 150^{\circ}$ C, $R_{G} = 4$ $\Omega$	10	V/ns	
P <sub>D</sub>	T <sub>C</sub> =25°C	400	W	
T <sub>J</sub> T <sub>JM</sub> T <sub>stg</sub>		-55 +150 150 -55 +150	°C °C	
T <sub>L</sub>	1.6 mm (0.062 in.) from case for 10 s	300	°C	
T <sub>SOLD</sub>	Plastic body for 10 s	260		
M <sub>d</sub>	Mounting torque (TO-3P)	1.13/10	Nm/lb.in.	
Weight	TO-3P	5.5	g	
	TO-268	5.0	g	

Symbol (T <sub>J</sub> = 25° C, t			Characteristic Values			
BV <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		250			V
$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250\mu A$		2.5		5.0	V
l <sub>GSS</sub>	$V_{GS} = \pm 20 V_{DC}, V_{DS} = 0$				±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T <sub>J</sub> = 125° C			25 250	μA μA
R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_{D} = 0.5 I_{D25}$ Pulse test, t \le 300 \mus, duty of	cycle d ≤ 2 %			49	mΩ

### TO-3P (IXTQ)



#### TO-268 (IXTT)



G = Gate D = Drain S = Source TAB = Drain

#### **Features**

- <sup>1</sup> International standard packages
- Unclamped Inductive Switching (UIS) rated
- 1 Low package inductance
  - easy to drive and to protect

#### **Advantages**

- <sup>1</sup> Easy to mount
- Space savings
- High power density

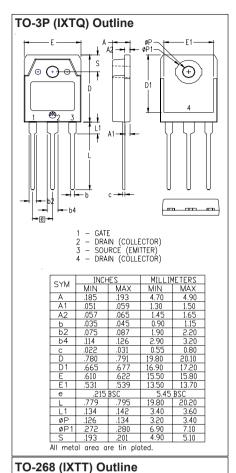


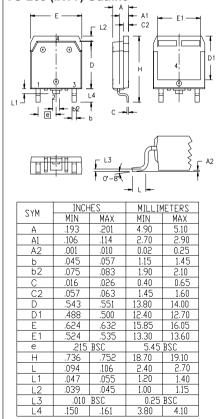
Symbo	ol	<b>Test Conditions</b> $(T_1 = 25^{\circ} C, ur)$	Characteristic Values (T = 25° C, unless otherwise specified)		
			in.	Тур.	Max.
$g_{fs}$		$V_{DS}$ = 10 V; $I_{D}$ = 0.5 $I_{D25}$ , pulse test	20	30	S
$\mathbf{C}_{iss}$	)			3450	pF
C <sub>oss</sub>	}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		640	pF
C <sub>rss</sub>	J			155	pF
$\mathbf{t}_{\text{d(on)}}$	)			21	ns
t <sub>r</sub>		$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = I_{D25}$		23	ns
$\mathbf{t}_{d(off)}$		$R_{G} = 4 \Omega \text{ (External)}$		60	ns
t,	J			20	ns
$\mathbf{Q}_{\mathrm{g(on)}}$	)			105	nC
$\mathbf{Q}_{gs}$	}	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_{D} = 0.5 I_{D25}$		24	nC
$\mathbf{Q}_{\mathrm{gd}}$	J			53	nC
R <sub>thJC</sub>		•			0.31° C/W
$R_{\text{thCS}}$		(TO-3P)		0.21	° C/W

#### Source-Drain Diode

Characteristic Values (T. = 25°C, unless otherwise specified)

Symbol	Test Conditions	Min.	Тур.	Max.	
I <sub>s</sub>	$V_{GS} = 0 V$			64	Α
I <sub>SM</sub>	Repetitive			160	Α
$\mathbf{V}_{\mathtt{SD}}$	$I_F = I_S$ , $V_{GS} = 0$ V, Pulse test, t ≤300 $\mu$ s, duty cycle d≤ 2 %			1.5	V
t <sub>rr</sub> Q <sub>RM</sub>	$I_F = 25 \text{ A}, -\text{di/dt} = 100 \text{ A/}\mu\text{s}$ $V_R = 100 \text{ V}, V_{GS} = 0 \text{ V}$		200 3.0		ns μC





8

0

0

0.5

Fig. 1. Output Characteristics

4

Fig. 2. Extended Output Characteristics @ 25°C 180 V<sub>GS</sub> = 10V 160 140 120 I<sub>D</sub> - Amperes 100 8V 80 7V 60 40 6V 20 5V 0 2 6 10 12 14 16 18 20 V<sub>DS</sub> - Volts

Fig. 3. Output Characteristics @ 125°C 64 V<sub>GS</sub> = 10V 56 9V 8V 48 ID - Amperes 40 32 6V 24 16 5V 8 0 0 2 3 4 5 6 7  $V_{D\ S}$  - Volts

1.5

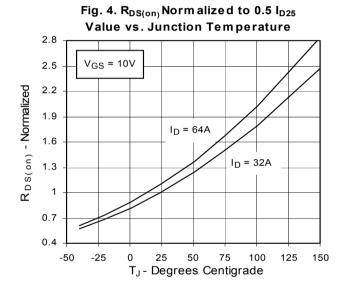
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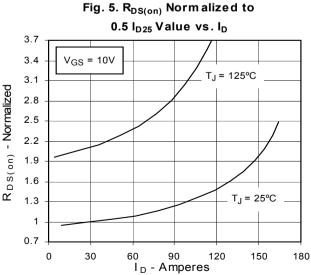
V<sub>DS</sub> - Volts

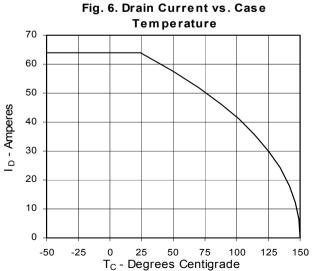
2.5

3

3.5







.po. 20

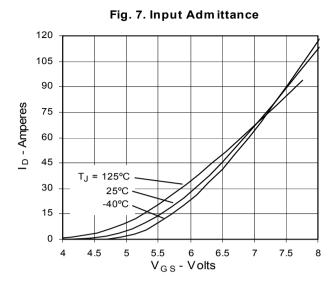
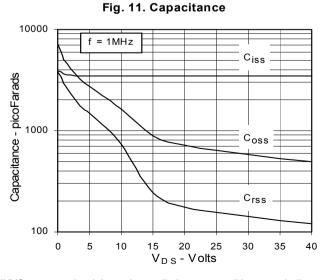
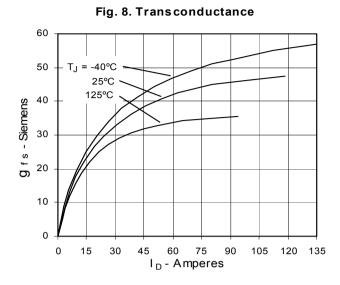
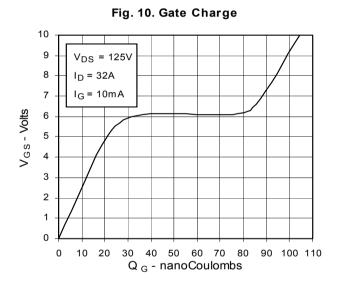
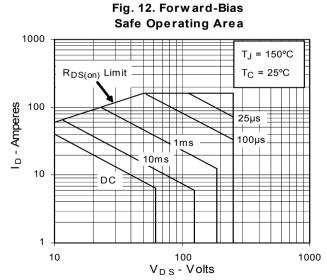


Fig. 9. Source Current vs. Source-To-Drain Voltage 180 150 120 Is - Amperes 90 60 T<sub>J</sub> = 125°C T<sub>J</sub> = 25°C 30  $^{0.8}$   $^{1}$   $^{1}$  V  $_{S\,D}$  - V olts 0.4 0.6 1.2 1.4









IXYS reserves the right to change limits, test conditions, and dimensions.



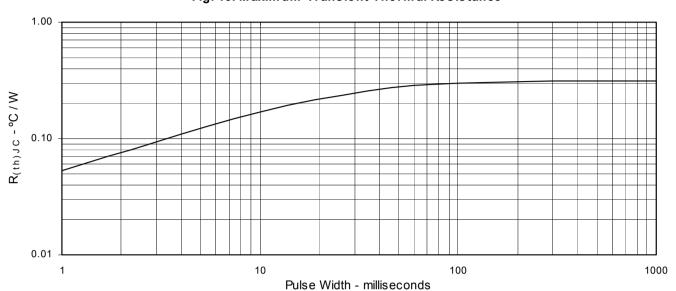


Fig. 13. Maximum Transient Thermal Resistance

